

isc Silicon NPN Darlington Power Transistor

BDX53B

DESCRIPTION

- · Collector-Emitter Sustaining Voltage-
- : V_{CEO(sus)}= 80V(Min)
- High DC Current Gain
- : h_{FE}= 750(Min) @I_C= 3A
- Low Collector Saturation Voltage
- : V_{CE(sat)} = 2.0 V(Max) @ I_C = 3.0 A
- Complement to Type BDX54B
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

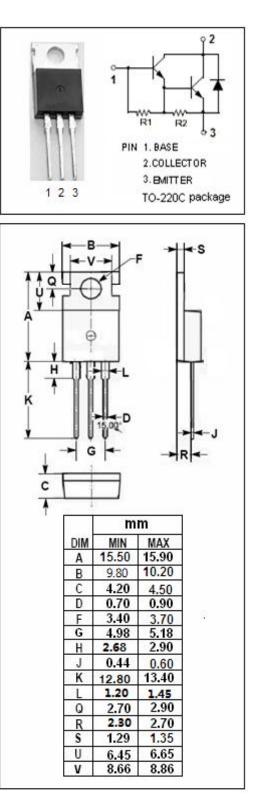
• Designed for general-purpose amplifier and low-speed switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	80	V
V _{CEO}	Collector-Emitter Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	8	А
I _{CP}	Collector Current-Peak	12	A
IB	Base Current-Continuous	0.2	А
Pc	Collector Power Dissipation @ T _C =25°C	60	w
TJ	Junction Temperature 1		°C
T _{stg}	Storage Temperature Range	-65~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case		°C/W



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 50mA; I _B = 0	80			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 12mA			2.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 12mA			2.5	V
V _{ECF}	C-E Diode Forward Voltage	I _F = 3A			2.5	V
І _{сво}	Collector Cutoff Current	V _{CB} = 80V; I _E = 0			0.2	mA
Ісео	Collector Cutoff Current	V _{CE} = 40V; I _B = 0			0.5	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			2.0	mA
h _{FE}	DC Current Gain	I _C = 3A ; V _{CE} = 3V	750			

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